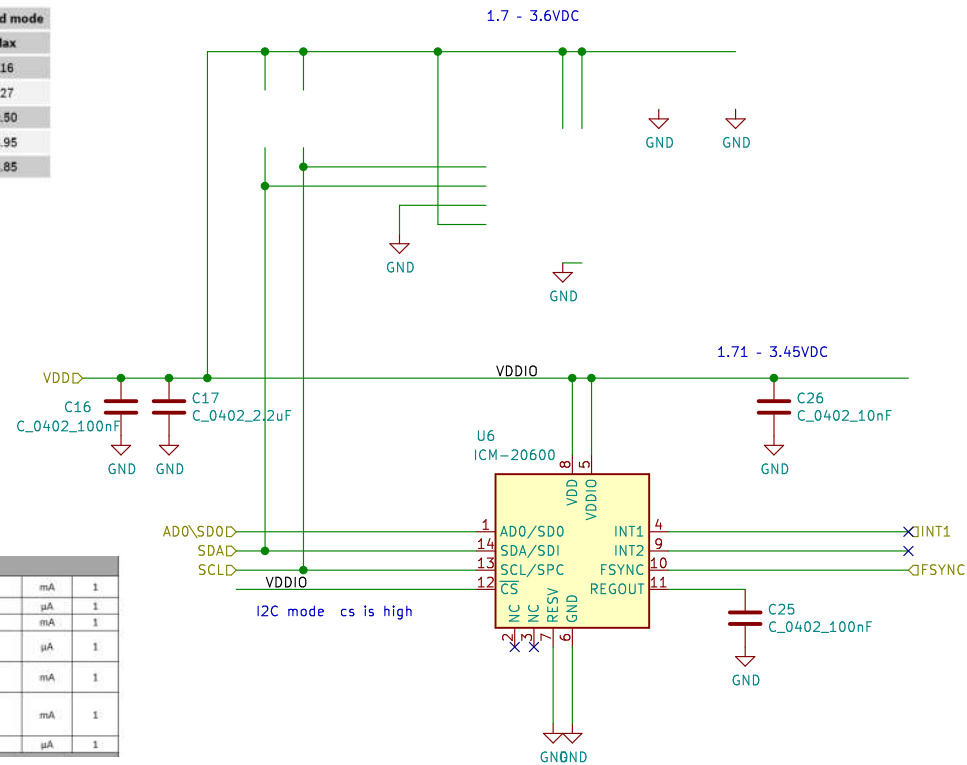


Table 12: Current consumption

Oversampling setting	Pressure oversampling	Temperature oversampling	I _{cc} [μA] @ 1 Hz forced mode	
			Typ	Max
Ultra low power	×1	×1	2.74	4.16
Low power	×2	×1	4.17	6.27
Standard resolution	×4	×1	7.02	10.50
High resolution	×8	×1	12.7	18.95
Ultra high resolution	×16	×2	24.8	36.85

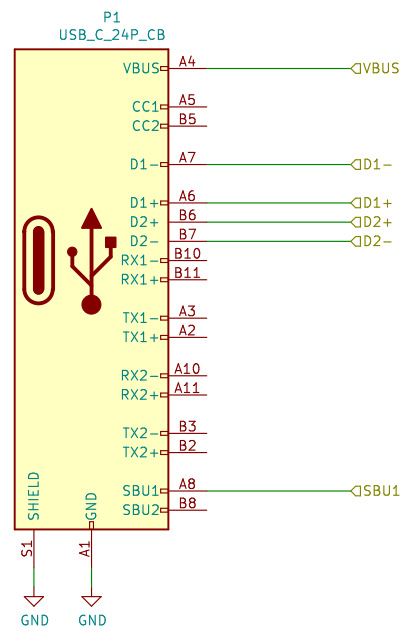
SUPPLY CURRENTS & BOOT TIME					
Low-Noise Mode	6-Axis Gyroscope + Accelerometer		2.79	mA	1
	3-Axis Accelerometer		321	μA	1
	3-Axis Gyroscope		2.55	mA	1
Accelerometer Low-Power Mode (Gyroscope disabled)	100 Hz ODR, 1x averaging		40	μA	1
Gyroscope Low-Power Mode (Accelerometer disabled)	100 Hz ODR, 1x averaging		1.08	mA	1
6-Axis Low-Power Mode (Gyroscope Low-Power Mode; Accelerometer Low-Noise Mode)	100 Hz ODR, 1x averaging		1.33	mA	1
Full-Chip Sleep Mode	At 25°C		6	μA	1

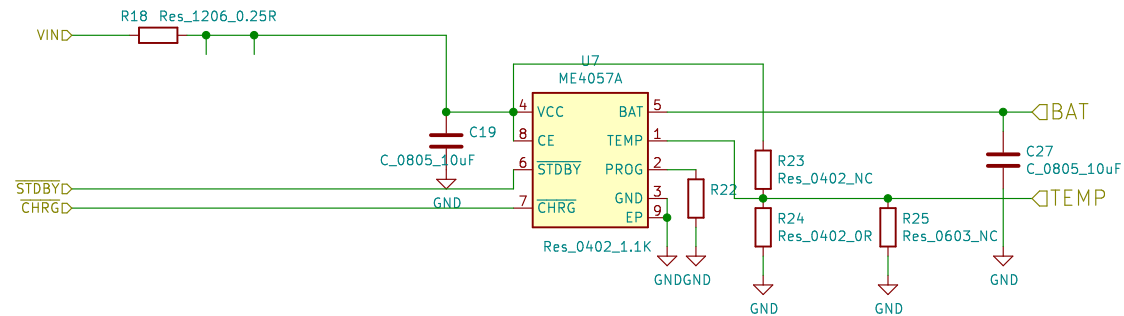


Interrupts carried on INT1 and INT2 pins are shown in the table below. If INT2 is not enabled, all interrupts are mapped to INT1.
the address of one of the devices should be b1101000 (pin AD0 is logic low) and the address of the other should be b1101001 (pin AD0 is logic high).

INTERRUPT NAME	MODULE
Motion Detection	INT2
FIFO Overflow	INT2
FIFO Watermark	INT1
Data Ready	INT1
FSYNC	INT2

Table 12. Table of interrupt Sources





产品型号	产品说明
ME4057ASPG	$V_{\text{FLOAT}} = 4.2\text{V}$
ME4057DSPG	$V_{\text{FLOAT}} = 4.34\text{V}$
ME4057ESPG	$V_{\text{FLOAT}} = 4.4\text{V}$

脚位说明

序号	名称	功 能
1	TEMP	电池温度检测 TEMP 外部连接一个温度检测电阻，用来监视电池温度。当 TEMP 脚电压低于 45% 或高于 80%VCC 电压时，意味着电池温度过高或者过低，充电停止。当外部不用温度检测功能时，可将 TEMP 直接接到 GND。
2	PROG	恒流充电电路和充电电流监测引脚。充电电流可以通过外接一个电阻 R _{PROG} 到地，来设置充电电流。充电电流公式： $I_{BAT} = \frac{V_{PROG}}{R_{PROG}} * 1100$
3	GND	地
4	V _{CC}	芯片输入引脚 提供电源给内部电路，当电源比 BAT 较电压低至 60mV 以内时，芯片内部关断，进入睡眠模式，电池漏电流低至 2μA。
5	BAT	电池连接引脚 连接电池到 BAT 引脚。BAT 引脚充电截止电压为 4.2V (4.34V)。
6	STDBY	充电截止状态指示 STDBY 当检测到充电截止时，内部开关下拉，其他状态此引脚为高阻态。
7	CHRG	开漏充电状态指示 当检测到电池正在充电时，CHRG 引脚内部开关下拉，其他状态此引脚为高阻态。
8	CE	芯片使能引脚 引脚拉高芯片开始正常工作，引脚拉低，芯片停止工作。CE 引脚可以被 TTL 或 CMOS 译码电路驱动。

I _{BAT}	充电电流 (电流模式 V _{BAT} =3.9V)	• R _{PROG} =2.2KΩ, 电流模式	450	500	550	mA
		• R _{PROG} =1.1KΩ, 电流模式	950	1000	1050	mA
		• 待机模式 V _{DET} =4.2V (ME4057ASP)/(ME4057BSP) V _{DET} =4.34V (ME4057DSP)	0	-2.5	-6	μA
		R _{PROG} 悬空	-	±1	±2	μA
I _{PROG}	涪流充电电流	睡眠模式, V _{CC} =0V	-	-1	-2	μA
		• V _{BAT} <V _{TRIM} , R _{PROG} =1.1KΩ	120	130	140	mA

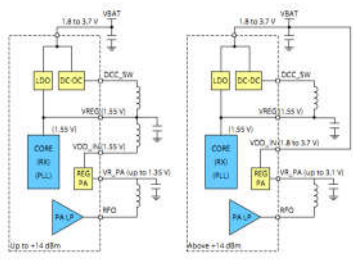
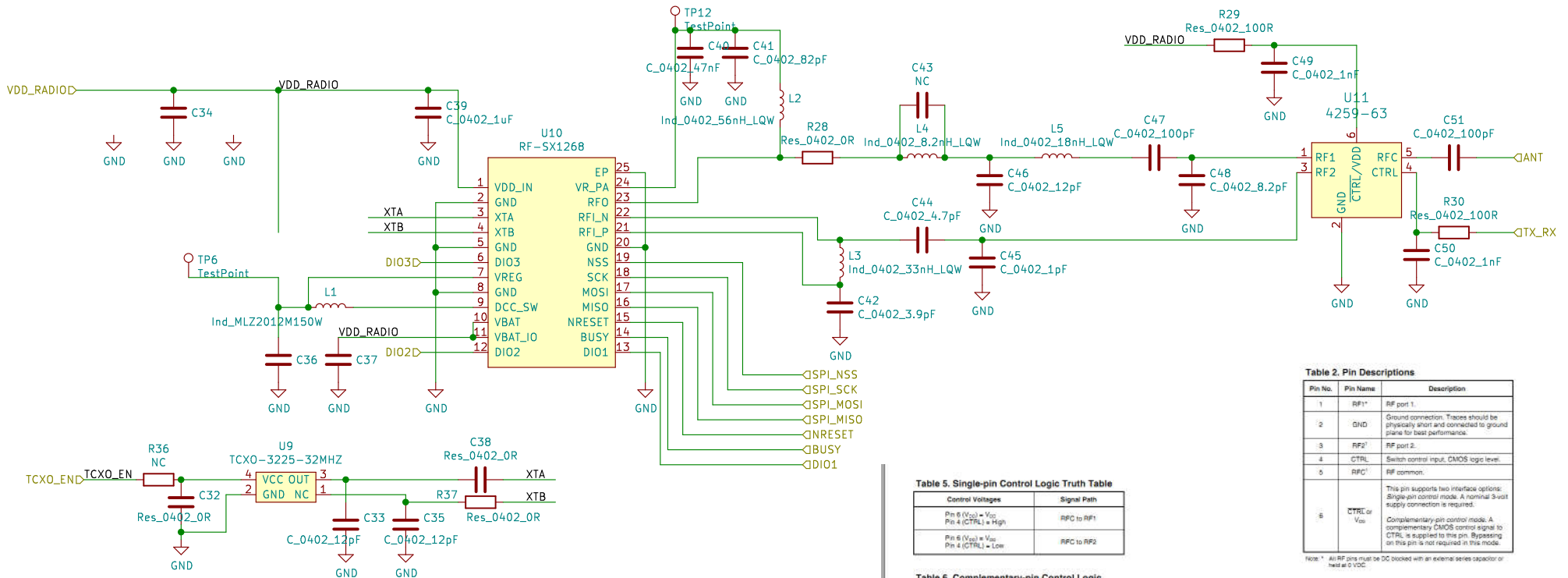


Figure 4-3: PA Supply Scheme in DC-DC Mode

4.4.3 Power Amplifier Summary

The following table summarizes the power amplifier optimization keys between both PA supply modes:

Table 4-4: Power Amplifier Summary

PA Summary	Conditions	Up to +14 dBm	Above +14 dBm
Max Power	with relevant matching and settings	+14 dBm	+22 dBm
IDDTX	at +22 dBm and 490 MHz	-	107 mA
	at +10 dBm and 780 MHz	20 mA	-
Output Power vs VBAT		flat from VBAT = 1.8 V to 3.7 V	VBAT = 3.1 V for +22 dBm VBAT = 2.7 V for +20 dBm VBAT = 1.8 V for +16 dBm
IDDTX vs VBAT		inversely proportional to VBAT, DC-DC buck converter is used for PA supply	-

Table 5. Single-pin Control Logic Truth Table

Control Voltages	Signal Path
Pin 6 (CTRL or V _{CC}) = High Pin 4 (CTRL) = High	RFC to RF1
Pin 6 (CTRL or V _{CC}) = High Pin 4 (CTRL) = Low	RFC to RF2

Table 6. Complementary-pin Control Logic Truth Table

Control Voltages	Signal Path
Pin 6 (CTRL or V _{CC}) = Low Pin 4 (CTRL) = High	RFC to RF1
Pin 6 (CTRL or V _{CC}) = High Pin 4 (CTRL) = Low	RFC to RF2

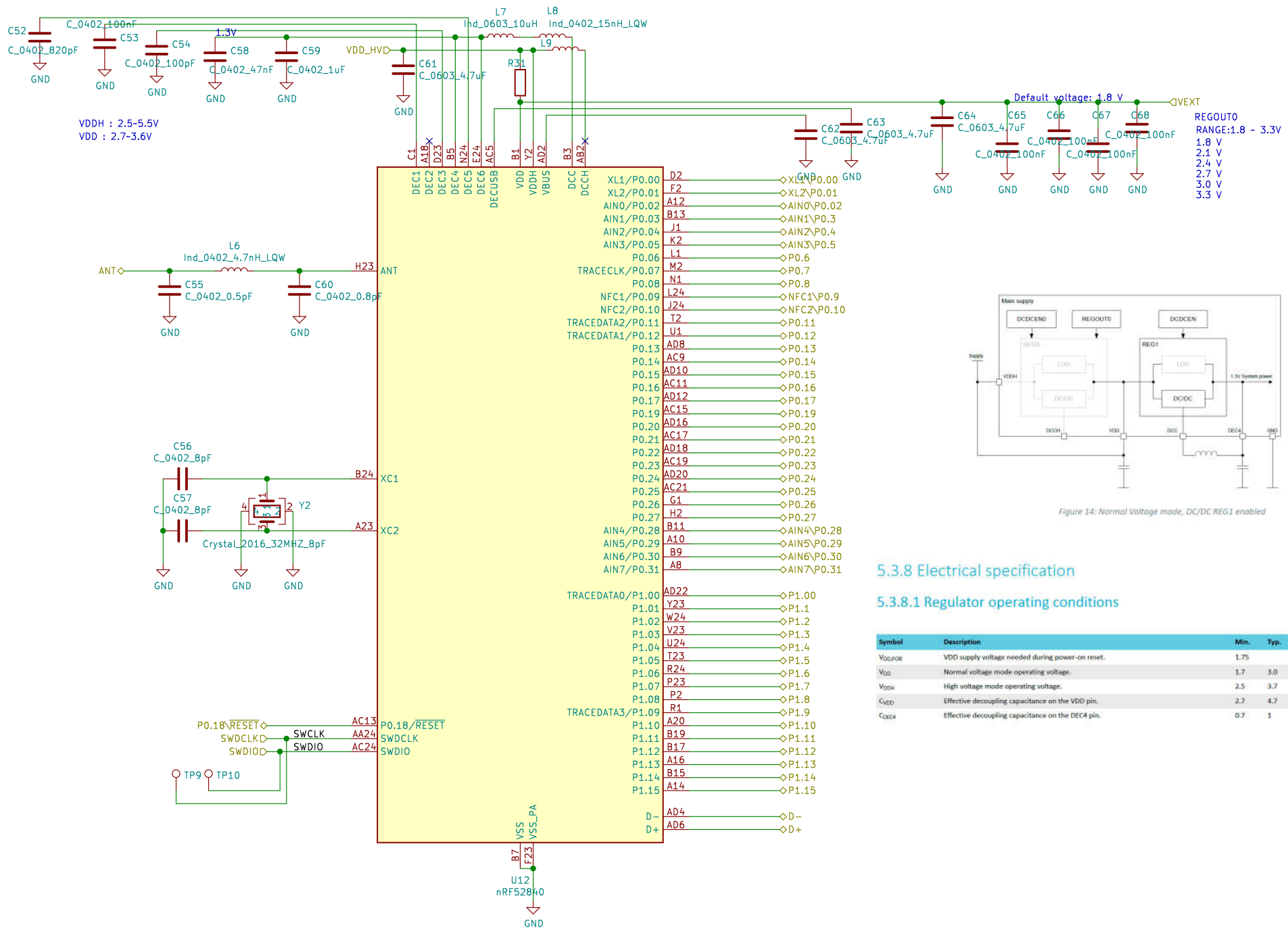
Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	RF1*	RF port 1.
2	GND	Ground connection. Traces should be physically short and connected to ground plane for best performance.
3	RF2*	RF port 2.
4	CTRL	Switch control input. CMOS logic level.
5	RF0*	RF common.
6	CTRL or V _{CC}	This pin supports two interface options: Single-pin control mode. A nominal 3-volt supply connection is required. Complementary-pin control mode. A complementary CMOS control signal to CTRL is supplied to this pin. Bypassing on this pin is not required in this mode.

Note: * All RF pins must be DC blocked with an external series capacitor or tied at 0 VDC.

Table 3. Operating Ranges

Parameter	Min	Typ	Max	Unit
V _{BAT} Power supply voltage	1.8	3.0	3.3	V
I _{DD} Power supply current (V _{BAT} = 3V, V _{CC} = 3V)	-	9	20	µA
Control voltage high	0.7x V _{DD}	-	-	V
Control voltage low	-	-	0.3x V _{DD}	V



5.3.8 Electrical specification

5.3.8.1 Regulator operating conditions

Symbol	Description	Min.	Typ.	Max.	Units
V _{DD,POR}	VDD supply voltage needed during power-on reset.	1.75			V
V _{DD}	Normal voltage mode operating voltage.	1.7	3.0	3.6	V
V _{DDH}	High voltage mode operating voltage.	2.5	3.7	5.5	V
C _{VDD}	Effective decoupling capacitance on the VDD pin.	2.7	4.7	5.5	µF
C _{DEC4}	Effective decoupling capacitance on the DEC4 pin.	0.7	1	1.3	µF

